NSN 5961-01-177-4717

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View Online at https://aerobasegroup.com/nsn/5961-01-177-4717 **Inclosure Material:** Metal **Overall Length:** 1.218 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-111 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 collector to base voltage, dc and 8.0 emitter to base voltage, dc and 120.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 37.5 watts small-signal input power, common-collector preset **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 wire hook Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

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